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Elnaz Akbari, Kia Jahanbin, Abdolkarim Afroozeh, P.Yupapin, Zolkafle Buntat

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Brief Review of Monolayer Molybdenum Disulfide Application in Gas Sensor

Elnaz Akbari^{1,2*}, Kia Jahanbin³, Abdolkarim Afroozeh⁴, P.Yupapin⁵,⁶, Zolkafle Buntat⁷ ¹Department for Management of Science and Technology Development, Ton Duc Thang University, Ho Chi Minh City, Vietnam ²Faculty of Electrical & Electronics Engineering, Ton Duc Thang University, Ho Chi Minh City, Vietnam ³Department of Computer, Kerman Branch, Islamic Azad University, Kerman, Iran ⁴Department of Engineering, University of Larestan, Lar, Iran ⁵Computational Optics Research Group, Advanced Institute of Materials Science, Ton Duc Thang University, District 7, Ho Chi Minh City, Veitnam ⁶Faculty of Electrical & Electronics Engineerig, Ton Duc Thang University, District 7, Ho Chi Minh City, Veitnam ⁷Institute of High Voltage & High Current, Faculty of Electrical Engineering, Universiti Teknologi Malaysia, Johor Bahru, 81310 Malaysia

Corresponding Author E-mail: elnaz.akbari@tdt.edu.vn

Abstract:

With the continuous increase in technological applications, the progress of new semiconductor materials continues to be a significant research field. In recent years, new materials such as molybdenum disulfide, has been researched as a substitute for graphene and silicon. The monolayer molybdenum disulfide (MoS_2), one of the promising 2D materials with a direct bandgap has high potential for applications in nano electronic devices, energy storage, photocatalysts, and chemical sensors. As such, this paper examines the present gas-sensing applications of MoS_2 and have been compared it with other nanomaterials.

Keywords: MoS₂, nano-electronics, gas sensor

1. Introduction

Since the discovery of graphene in 2004, two-dimensional (2D) layered materials have drawn a lot of attention from materials scientists. With fascinating unusual properties, 2D layered materials could be used in field-effect transistors, photosensors, photovoltaics, ultracapacitors, composite materials, and photocatalysts. Typically, 2D layered materials have strong in-plane bonds and weak van der Waals bonds between the layers. Interestingly, physical, chemical, and

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